



**东沃电子**  
DOWOSEMI

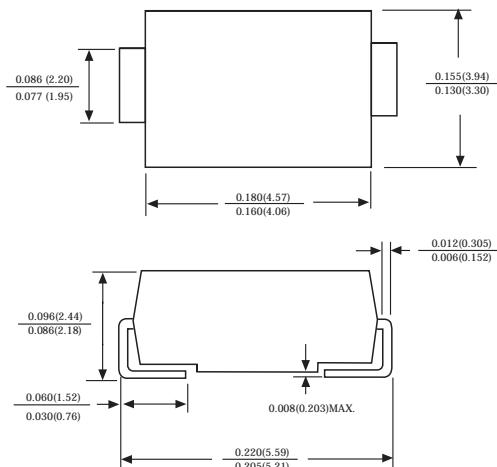
# SS52 THRU SS520

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts    Forward Current - 5.0 Amperes

### SMB

**DO-214AA**



Dimensions in inches and (millimeters)

### FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 250°C/10 seconds at terminals

### MECHANICAL DATA

**Case:** JEDEC DO-214AA molded plastic body  
**Terminals:** leads solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.005 ounce, 0.138 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	SS32	SS53	SS54	SS55	SS56	SS38	SS510	SS515	SS520	UNITS		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	150	200	VOLTS		
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	105	140	VOLTS		
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	150	200	VOLTS		
Maximum average forward rectified current at T <sub>L</sub> (see fig.1)	I <sub>(AV)</sub>	5.0								Amps			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	150.0								Amps			
Maximum instantaneous forward voltage at 5.0A	V <sub>F</sub>	0.45	0.55	0.70	0.85				Volts				
Maximum DC reverse current T <sub>A</sub> =25°C at rated DC blocking voltage T <sub>A</sub> =100°C	I <sub>R</sub>	0.5		20		10		mA					
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	800			500				pF				
Typical thermal resistance (NOTE 2)	R <sub>QJA</sub>	55.0						°C/W					
Operating junction temperature range	T <sub>J</sub>	-65 to +125			-65 to +150				°C				
Storage temperature range	T <sub>STG</sub>	-65 to +150						°C					

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.4x0.4" (10x10mm) copper pad areas



RATINGS AND CHARACTERISTIC CURVES SS52 THRU SS520

AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

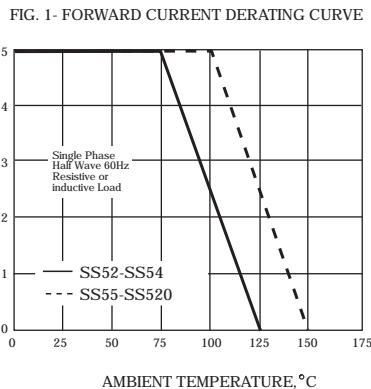
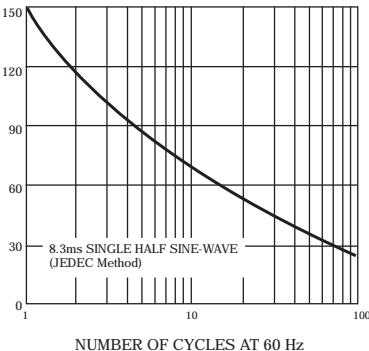
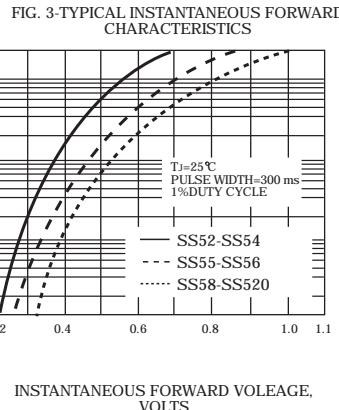


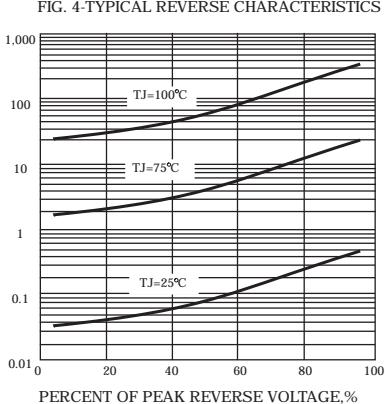
FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



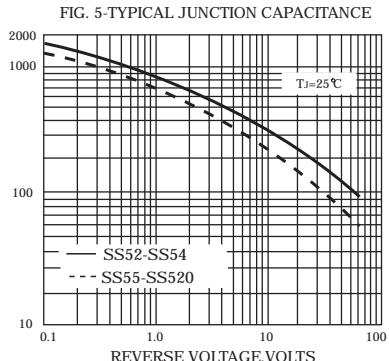
INSTANTANEOUS FORWARD CURRENT AMPERES



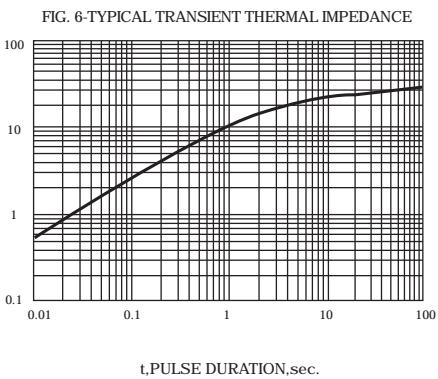
INSTANTANEOUS REVERSE CURRENT,  
MILLIAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE,  
°C/W



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